

6MHz CMOS Rail-to-Rail IO Opamps

General Description

The LMV82X have a high gain-bandwidth product of 6MHz, a slew rate of $4.2V/\mu s$, and a quiescent current of $470\mu A$ per amplifier at 5V. The LMV82X are designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for LMV82X. They are specified over the extended industrial temperature range ($-40^{\circ}C$ to $+125^{\circ}C$). The operating range is from 2.1V to 5.5V. The LMV821 single is available in Green SC70-5, SOT23-5 and SOP-8 packages.

The LMV822 dual is available in Green SOP-8 and MSOP-8 packages. The LMV824 Quad is available in Green SOP-14 and TSSOP-14 packages.

Features

- Single-Supply Operation from +2.1V~+5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 6MHz (Typ)
- Low Input Bias Current: 1pA (Typ)
- Low Offset Voltage: 3.5mV (Max)
- Quiescent Current: 470µA per Amplifier (Typ)
- Operating Temperature: -40°C ~ +125°C
- Small Package:

LMV821 Available in SOT23-5, SOP-8 and SC70-5 Packages

LMV822 Available in SOP-8 and MSOP-8 Packages LMV824 Available in SOP-14 and TSSOP-14 Packages

Applications

- Sensors
- Active Filters
- Cellular and Cordless Phones
- Laptops and PDAs

- Audio
- Handheld Test Equipment
- Battery-Powered Instrumentation
- A/D Converters

Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
LMV821IDBVRG	SOT23-5	V821	REEL	3000pcs/reel
LMV821IDCKRG	SC70-5	V821	REEL	3000pcs/reel
LMV821IDRG	SOP8	LMV821	REEL	2500pcs/reel
LMV822IDRG	SOP8	LMV822	REEL	2500pcs/reel
LMV822IDGKRG	MSOP8	V822	REEL	3000pcs/reel
LMV824IDRG	SOP14	LMV824	REEL	2500pcs/reel
LMV824IPWRG	TSSOP14	LMV824	REEL	2500pcs/reel



Pin Configuration

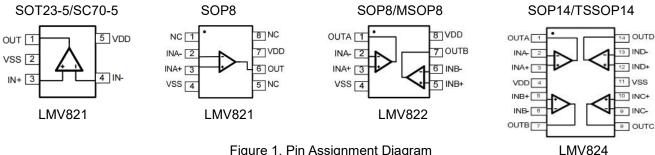


Figure 1. Pin Assignment Diagram

Absolute Maximum Ratings

Condition		Min	Max			
Power Supply Voltage (VDD to Vss)		-0.5V	+7.5V			
Analog Input Voltage (IN+ or IN-)		Vss-0.5V	VDD+0.5V			
PDB Input Voltage	Vss-0.5V	+7V				
Operating Temperature Range	-40°C	+125°C				
Junction Temperature		ON JO	+160°C			
Storage Temperature Range	Storage Temperature Range					
Lead Temperature (soldering, 10sec)	178	Oly	+260°C			
	SOP-8, θJA	"THIS	125°C/W			
	MSOP-8, θJA	20.	216°C/W			
Package Thermal Resistance (TA=+25 ℃)	SOT23-5, θJA	-	190°C/W			
	SC70-5, θJA	-	333°C/W			
F0D 0	НВМ	-	8KV			
ESD Susceptibility	MM	-	400V			

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational

sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



Electrical Characteristics

(At Vs=5V, TA = +25 $^{\circ}$ C, VCM = VS/2, RL = 600 Ω , unless otherwise noted.)

				LM	V821/82	2/824		
DADAMETER	CONDITIONS	TYP	1	MIN/MA	X OVER	TEMPE	RATUR	E
PARAMETER	CONDITIONS	+25℃	+25 ℃	0℃ to 70℃	-40℃ To 85℃	-40 ℃ to 125℃	UNITS	MIN /
INPUT CHARACTERISTICS								
Input Offset Voltage (VOS)		8.0	3.5	3.9	4.3	4.6	mV	MAX
Input Bias Current (IB)		1					pА	TYP
Input Offset Current (IOS)		1					pА	TYP
Input Common Mode Voltage Range (VCM)	VS = 5.5V	-0.1 to					V	TYP
		+5.6						
Common Mode Rejection Ratio (CMRR)	VS = 5.5V, VCM = -0.1V to 4V	90	73	70	70	65	dB	MIN
	VS = 5.5V, VCM = -0.1V to 5.6V	83	X				dB	MIN
Open-Loop Voltage Gain (AOL)	$RL = 600\Omega, VO = 0.15V \text{ to}$ 4.85V	97	90	87	86	79	dB	MIN
	$RL = 10k\Omega, VO = 0.05V \text{ to } 4.95V$	108	10	C.			dB	MIN
Input Offset Voltage Drift			DITIO					
(ΔVOS/ΔΤ)		2.4	7				μV/°C	TYP
OUTPUT CHARACTERISTICS								
Output Voltage Swing from Rail	RL = 600Ω	0.1					V	TYP
	$RL = 10k\Omega$	0.015					V	TYP
Output Current (IOUT)		53	49	45	40	35	mA	MIN
Closed-Loop Output Impedance	f = 200kHz, G = 1	3					Ω	TYP
POWER-DOWN DISABLE								
Turn-On Time		4					μs	TYP
Turn-Off Time		1.2					μs	TYP
POWER SUPPLY								
Operating Voltage Range			2.1 5.5	2.1 5.5	2.1 5.5	2.1 5.5	V V	MIN MAX
Power Supply Rejection Ratio (PSRR) Quiescent Current/Amplifier (IQ)	VS = +2.5V to +5.5VV _{CM} = (-VS) + 0.5V I _{OUT} = 0	91 470	74 650	72 727	72 750	68 815	dΒμΑ	MIN MAX



Electrical Characteristics

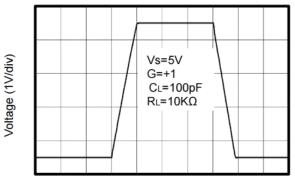
(At Vs=5V, TA = +25 $^{\circ}$ C, VCM = VS/2, RL = 600 Ω , unless otherwise noted.)

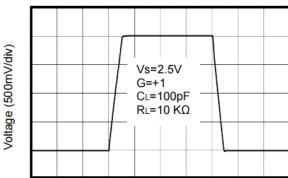
		LMV821/822/824									
PARAMETER	CONDITIONS	TYP	P MIN/MAX OVER TEMPERATURE								
PARAWETER		+25 ℃	+25 ℃	0℃ to 70℃	-40℃ to 85℃	-40℃to 125℃	UNITS	MIN/ MAX			
DYNAMIC PERFORMANCE											
Gain-Bandwidth Product (GBP)	RL = 10kΩ, CL = 100pF	6					MHz	TYP			
Phase Margin (φO)	RL = 10kΩ, CL = 100pF	53					Degrees	TYP			
Full Power Bandwidth (BWP)	<1% distortion, R _L = 600Ω	250					kHz	TYP			
Slew Rate (SR)	G = +1, 2V Step, RL = 10kΩ	4.2					V/µs	TYP			
Settling Time to 0.1% (tS)	G = +1, 2V Step, RL = 600Ω	0.4					μs	TYP			
Overload Recovery Time	V _{IN} ·Gain = VS, R _L = 600Ω	2.5					μs	TYP			
NOISE PERFORMANCE											
Voltage Noise Density (en)	f = 1kHz	13		X.			$nV\sqrt{HZ}$	TYP			
	f = 10kHz	9.5		12			nV√HZ	TYP			



Typical Performance characteristics

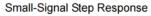
(At Vs=5V, TA = +25 $^{\circ}$ C, VCM = VS/2, RL = 600 Ω , unless otherwise noted.) Large-Signal Step Response Large-Signal Step Response

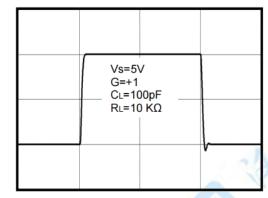




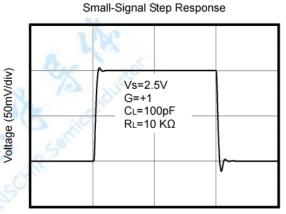
Time (1µs/div)

Time (1µs/div)





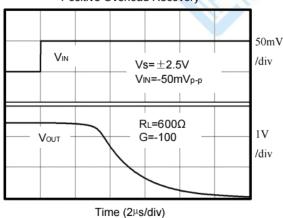
Voltage (50mV/div)

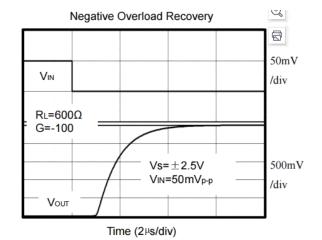


Time (1µs/div)

Time (1µs/div)



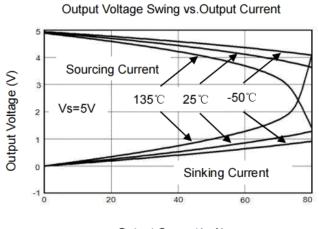




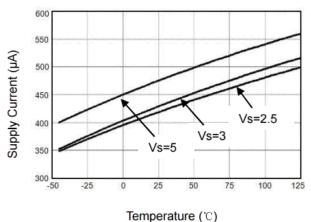


Typical Performance characteristics

(At Vs=5V, TA = +25°C, VCM = VS/2, RL = 600 Ω , unless otherwise noted.)

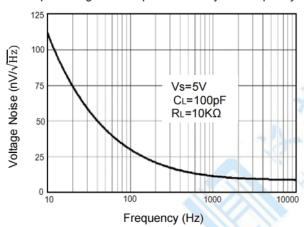


Supply Current vs. Temperature

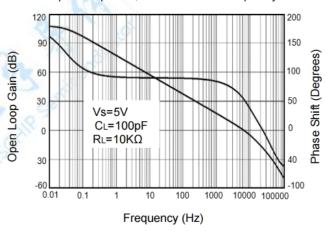


Output Current(mA)

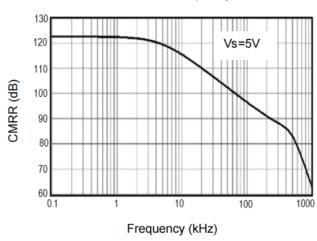




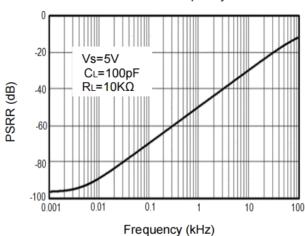
Open Loop Gain, Phase Shift vs. Frequency



CMRR vs. Frequency



PSRR vs. Frequency





Application Note

Size

LMV82X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the LMV82X series packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

LMV82X series operates from a single 2.1V to 5.5V supply or dual ± 1.05 V to ± 2.75 V supplies. For best performance, a 0.1μ F ceramic capacitor should be placed close to the VDD pin in single supply operation. For dual supply operation, both VDD and VSS supplies should be bypassed to ground with separate 0.1μ F ceramic capacitors.

Low Supply Current

The low supply current (typical 470µA per channel) of LMV82X series will help to maximize battery life . They are ideal for battery powered systems.

Operating Voltage

LMV82X series operate under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40 oC to +125 oC. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime.

Rail-to-Rail Input

The input common-mode range of LMV82X series extends 100mV beyond the supply rails (VSS-0.1V to VDD+0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of LMV82X series can typically swing to less than 2mV from supply rail in light resistive loads (>100k Ω), and 60mV of supply rail in moderate resistive loads (10k Ω).

Capacitive Load Tolerance

The LMV82x family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain.

Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

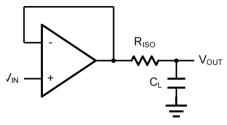


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor



The bigger the RISO resistor value, the more stable VOUT will be. However, if there is a resistive load RL in parallel with the capacitive load, a voltage divider (proportional to RISO/RL) is formed, this will result in a gain error. The circuit in Figure 3 is an improvement to the one in Figure 2. RF provides the DC accuracy by feed-forward the VIN to RL. CF and RISO serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of CF. This in turn will slow down the pulse response.

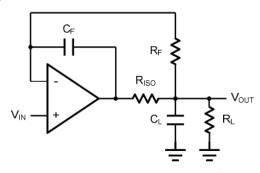


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy



Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4.

shown the differential amplifier using LMV82X.

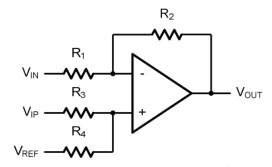


Figure 4. Differential Amplifier

$$V_{OUT} = (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_4}{R_1} V_{IN} - \frac{R2}{R1} V_{IP} + (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_3}{R_1} V_{REF}$$

If the resistor ratios are equal (i.e. R1=R3 and R2=R4), then

$$V_{OUT} = \frac{R_2}{R_1}(V_{IP} - V_{IN}) + V_{REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by -R2/R1. The filter has a -20dB/decade roll-off after its corner frequency $fC=1/(2\pi R3C1)$.

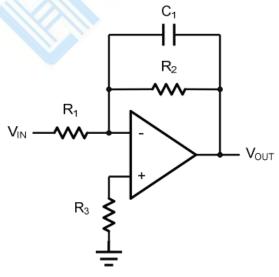


Figure 5. Low Pass Active Filter



Instrumentation Amplifier

The triple LMV82X can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R_2/R_1 . The two differential voltage followers assure the high input impedance of the amplifier.

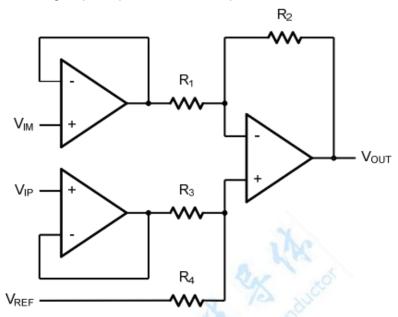
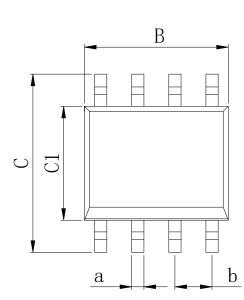


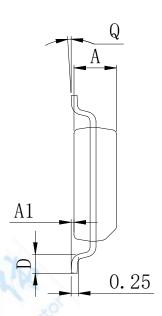
Figure 6. Instrument Amplifier



Physical Dimensions

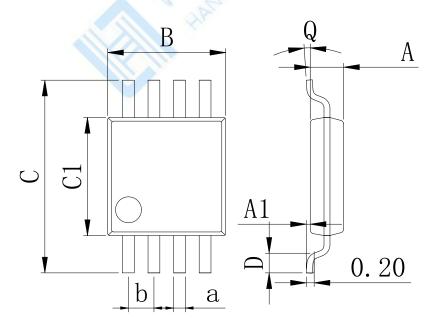
 $SOP8_{\ (150mil)}$





Dimensions In Millimeters(SOP8)											
Symbol:	А	A1	В	С	C1	D	Q	а	b		
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC		
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.27 BSC		

MSOP8

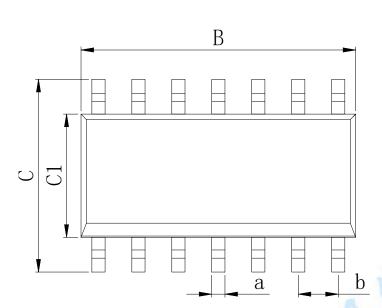


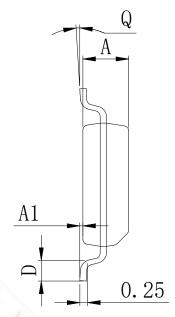
Dimensions In Millimeters(MSOP8)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b		
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65.000		
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	0.65 BSC		



Physical Dimensions

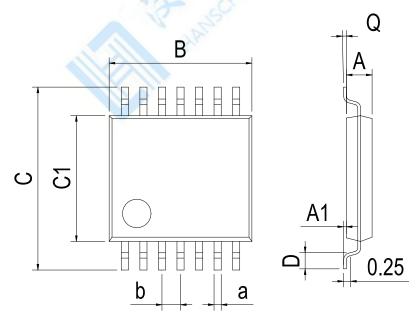
SOP14





Dimensions In Millimeters(SOP14)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b		
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1.27 BSC		
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 000		

TSSOP14

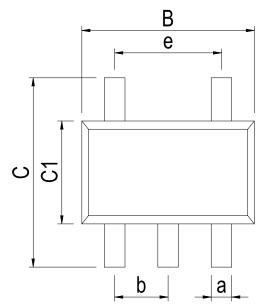


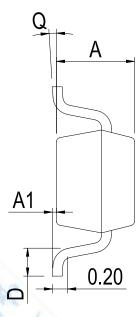
Dimensions In M	Dimensions In Millimeters(TSSOP14)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b			
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC			
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.05 BSC			



Physical Dimensions

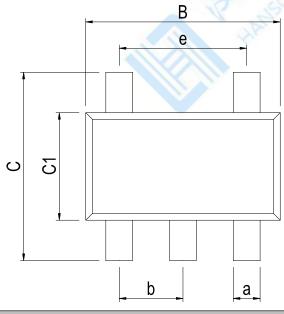
SOT23-5

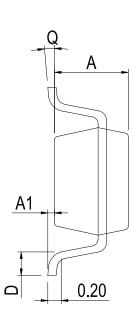




Dimensions In	Dimensions In Millimeters(SOT23-5)												
Symbol:	Α	A1	В	С	C1	D	Q	а	b	е			
Min:	1.05	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.95 BSC	1.90 BSC			
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.40	0.95 650				

SC70-5





Dimensions In Millimeters(SC70-5)											
Symbol:	А	A1	В	С	C1	D	Q	а	b	е	
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.30	0.65	1.30 BSC	
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.40	BSC	1.30 BSC	



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